Ligand-field helical luminescence in a 2D ferromagnetic insulator

Kyle L. Seyler[1], Ding Zhong[1], Dahlia R. Klein[2], Shiyuan Gao[3], Xiaoou Zhang[4], Bevin Huang[1], Efrén Navarro-Moratalla[2], Li Yang[3], David H. Cobden [1], Michael A. McGuire[5], Wang Yao [6], Di Xiao[4], Pablo Jarillo-Herrero[2]* and Xiaodong Xu [1,7]*

Bulk chromium tri-iodide (CrI_3) has long been known as a layered van der Waals ferromagnet[1]. However, its monolayer form was only recently isolated and confirmed to be a truly two-dimensional (2D) ferromagnet[2], providing a new platform for investigating light–matter interactions and magneto-optical phenomena in the atomically thin limit. Here, we report spontaneous circularly polarized photoluminescence in monolayer CrI_3 under linearly polarized excitation, with helicity determined by the monolayer magnetization direction. In contrast, the bilayer CrI_3 photoluminescence exhibits vanishing circular polarization, supporting the recently uncovered anomalous antiferromagnetic interlayer coupling in CrI_3 bilayers[2]. Distinct from the Wannier–Mott excitons that dominate the optical response in well-known 2D van der Waals semiconductors[3], our absorption and layer-dependent photoluminescence measurements reveal the importance of ligand-field and charge-transfer transitions to the optoelectronic response of atomically thin CrI_3. We attribute the photoluminescence to a parity-forbidden d-d transition characteristic of Cr^{3+} complexes, which displays broad linewidth due to strong vibronic coupling and thickness-independent peak energy due to its localized molecular orbital nature.

Van der Waals layered materials offer fascinating opportunities for studying light–matter interactions in the 2D limit. For instance, monolayer semiconducting transition metal dichalcogenides (for example, WSe_2) enable coupling between the helicity of light and the valley degree of freedom[4]. In all non-metallic 2D materials to date, it has been established that tightly bound Wannier–Mott excitons dominate the intrinsic optical response[3], and there has been rapid progress in studying 2D excitonic interactions, dynamics and spin/valley physics[3,5]. However, none of these 2D materials possesses long-range magnetic order. A monolayer semiconductor or insulator with intrinsic magnetism would enable the study of novel photo-physical phenomena and the interplay with underlying magnetic order, possibly involving physics incompatible with the Wannier–Mott excitonic picture.

On the other hand, the exploration of ferromagnetism in non-metallic bulk materials has a long history. Early studies examined the intrinsic ferromagnetic ordering of a variety of insulating and semiconducting materials, including, for example, the ferrites and ferrospinels[6], Cr trihalides[7], Eu chalcogenides[8] and Cr spinels[9]. Later, with the introduction of magnetic dopants into non-magnetic II–VI and III–V semiconductors, diluted magnetic semiconductors captured widespread attention[10], boosted by the discovery of ferromagnetism in Mn-doped InAs (ref. [11]) and GaAs (ref. [1]) in the 1990s[12]. Central to progress in these fields, optical experiments have led to a deep understanding of electronic structure, magnetization dynamics and interactions between magnetism and light[8,13–15]. While the fascinating physics in the quantum structures of diluted magnetic semiconductors has propelled spintronics research over the last few decades[16], there has been a comparative lack of non-metallic nanoscale materials hosting intrinsic magnetism.

Recently, several van der Waals magnetic insulators have emerged as a promising platform for exploring light–matter interactions in the monolayer limit[2,17,18]. In particular, a magneto-optical Kerr effect study[2] revealed 2D ferromagnetism in monolayer CrI_3 (Fig. 1a). Historically, the bulk chromium trihalides were found to behave as Mott insulators with an optical response governed by ligand-field and charge-transfer transitions[13,19–22], which are highly localized photo-excitations between molecular orbitals. Therefore, atomically thin chromium trihalides may provide a new platform from which to study 2D optical physics under the influence of intrinsic magnetic ordering beyond the excitonic picture. In this work, we reveal magnetization-determined ligand-field transitions in 2D ferromagnetic CrI_3 by magneto-photoluminescence (PL) and reflection spectroscopy.

We prepared monolayer CrI_3 on sapphire substrates by mechanical exfoliation of bulk crystals. For the PL experiments, we excited with a linearly polarized laser at 1.96 eV and analysed the circularly polarized PL components (see Methods). All measurements were done under normal incidence excitation and collection. We first measured the monolayer CrI_3 PL at 75 K, above the Curie temperature (T_C) of 45 K (ref. [2]), without applying magnetic field. As shown in Fig. 1b, there is a single broad emission feature centred at ~1.1 eV with a full-width at half-maximum of about 180 meV. We observed no other PL features at higher energy. The red and blue spectra correspond to σ^+ and σ^- circularly polarized PL, respectively. The two components are indistinguishable, which is consistent with the absence of magnetic order above T_C.

[1]Department of Physics, University of Washington, Seattle, WA, USA. [2]Department of Physics, Massachusetts Institute of Technology, Cambridge, MA, USA. [3]Department of Physics, Washington University, St Louis, MO, USA. [4]Department of Physics, Carnegie Mellon University, Pittsburgh, PA, USA. [5]Materials Science and Technology Division, Oak Ridge National Laboratory, Oak Ridge, TN, USA. [6]Department of Physics and Center of Theoretical and Computational Physics, University of Hong Kong, Hong Kong, China. [7]Department of Materials Science and Engineering, University of Washington, Seattle, WA, USA. *e-mail: pjarillo@mit.edu; xuxd@uw.edu
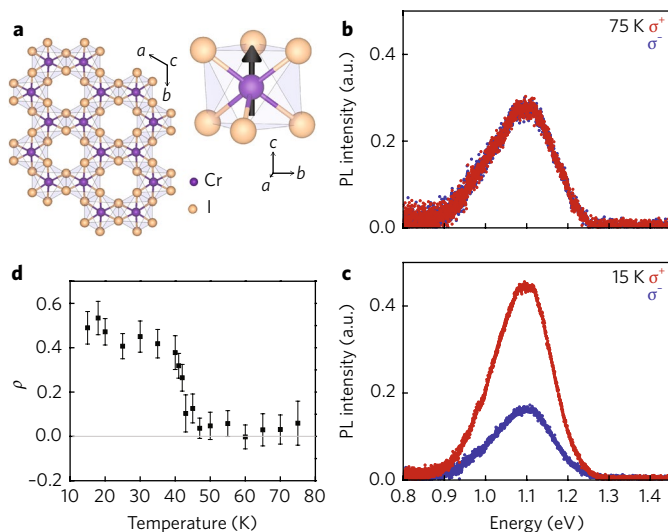
Fig. 1 | Spontaneous circularly polarized luminescence from monolayer CrI₃. a, Top view of the crystal structure of CrI_3 (left) and side view (right) depicting a single Cr site with an arrow representing its out-of-plane magnetic moment. **b**, Photoluminescence (PL) spectrum for σ^+ (red) and σ^- (blue) circularly polarized PL from a monolayer at 75 K. The excitation is linearly polarized. **c**, Same as **b**, but at 15 K. **d**, Temperature dependence of the degree of PL circular polarization (ρ) at 0 T from 75 to 15 K. The error bars show the standard deviation of the polarization at the peak. No external magnetic field was applied while acquiring the data in **b**–**d**.

Remarkably, on cooling to 15 K (well below T_C) in the absence of a magnetic field, we observe that the σ^+ and σ^- PL diverge in intensity, with σ^+ much brighter than σ^- (Fig. 1c). Defining the PL circular polarization, $\rho = \frac{I_+ - I_-}{I_+ + I_-}$, where $I_\pm$ is the peak intensity of $\sigma^\pm$ PL, we find $\rho \approx 0.45$. Since the linearly polarized excitation does not break the time-reversal symmetry of the system, the observation of net circular emission demonstrates the appearance of spontaneous out-of-plane magnetic ordering in monolayer CrI_3. While the peak narrows slightly (~10%) on cooling from 75 K to 15 K, its position does not change. Any energy splitting between the two polarizations is smaller than ~1 meV and unresolvable. The temperature dependence of ρ is shown in Fig. 1e. The onset of finite ρ at 45 K is consistent with T_C for a monolayer[2].

We next explore the effect of an applied out-of-plane magnetic field. Figure 2a shows the circularly polarized PL spectra at +0.5 T. Here the polarization is reversed relative to that shown in Fig. 1c (which was taken at zero field), due to a flip in the magnetization by the applied field. If the field is then lowered to 0 T, the spectra remain unchanged (Fig. 2b). When the opposite field, −0.5 T, is then applied, the magnetization is reversed again and the PL returns to its original state with a stronger σ^+ component than σ^-. This state is in turn preserved when the field is returned to zero (Fig. 2c,d). Additional data demonstrating this behaviour for a monolayer on a SiO_2/Si substrate are presented in Supplementary Section 1. We show ρ over a cycle of the magnetic field in Fig. 2e, where the observed hysteresis loop is clearly the hallmark of ferromagnetic behaviour. The saturation polarization is ± 0.5, and the coercive field is ~55 mT. Both circular polarization components show a linear power dependence (Supplementary Section 2), leading to a power-independent ρ.

The field-dependent measurements unambiguously demonstrate that the helicity of the CrI_3 PL is determined by its magnetic ordering, and thus that measurement of PL helicity can be used as a simple probe of its magnetic phases. Figure 3a–c presents the

circular polarization-resolved PL from a bilayer of CrI_3 at 15 K, at magnetic fields −1, 0 and +1 T respectively. We see strong circularly polarized PL at ±1 T (Fig. 3a,c), consistent with full spin polarization in bilayer CrI_3 at such high fields. In contrast with the monolayer, no net circular polarization is seen at zero field (Fig. 3b), which implies vanishing net out-of-plane magnetization. As shown in Fig. 3d, the polarization ρ is negligible between ±0.65 T and jumps abruptly to a value of −0.5 above 0.65 T and +0.5 below −0.65 T. This magnetic-field-dependent PL polarization forms a close parallel to the magneto-optical Kerr effect response in ref. [2], which also vanishes in the same field range. The consistency of the results for these two distinct experimental probes reinforces the interpretation that at low fields, bilayer CrI_3 consists of two ferromagnetic monolayers that are antiferromagnetically coupled.

What is the origin of luminescence in atomically thin CrI_3? In well-studied 2D semiconductors, such as WSe_2, the photo-response can be described by band-to-band transitions with strong excitonic effects. Tightly bound Wannier–Mott excitons dominate the optical spectrum[3]. In CrI_3, however, the 3d electrons are much more spatially localized, and thus to understand the optical response, a molecular orbital approach is more suitable. In fact, ligand field theory, which predicts intra-atomic d–d transitions and higher-energy charge-transfer transitions within metal–ligand complexes[23], has previously been used to interpret the optical spectra of bulk transition metal halides (refs [3–7]). While prior studies have focused on absorption/reflection in $CrCl_3$ and $CrBr_3$, there are few reports on the optical properties of CrI_3 (refs [1,3,19]), and none examining the PL. Furthermore, all previous work was limited to bulk crystals containing thousands of layers. We now present evidence that these intrinsic localized photo-excitations dominate in 2D CrI_3.

We first reiterate that the monolayer PL intensity is linear in excitation power, as illustrated in Supplementary Fig. 2. Taken together with the tight link between the PL helicity and layer-dependent magnetic phases, this rules out the possibility that the dominant PL contribution is from defect-bound excitons, which tend towards saturation at higher excitation intensity and are often seen in the low-energy PL spectra of other 2D semiconductors[3,24]. To investigate the electronic response more broadly, we measured the differential reflectance of monolayer CrI_3 on sapphire (Fig. 4a), which is proportional to its absorbance[25]. There is a weak peak near 1.5 eV along with stronger features around 2 eV and 2.7 eV. Using the ligand-field framework, we can attribute the 2.7 eV peak as well as the strongest two peaks near 2 eV to dipole-allowed ligand-to-metal charge-transfer (LMCT) transitions between the iodine 5p orbitals and the Cr^{3+} 3d orbitals (Supplementary Sections 3 and 4). The 1.5 eV transition has not been discussed much before in the literature. As a result of the approximate octahedral symmetry of the iodine ligands around each Cr^{3+} site (Fig. 1a), the d^3 configuration (^4F term) in isolated Cr^{3+} splits into an $^4A_2$ ground state and $^4T_2$ and $^4T_1$ excited states of the t_{2g} and e_g orbitals in CrI_3. We assign the 1.5 eV peak to the lowest energy transition between these levels, from $^4A_2$ to $^4T_2$. Despite being electric-dipole-forbidden by the Laporte parity selection rule, d–d transitions can become weakly allowed by mixing with odd-parity states, such as produced by phonons[26]. In addition, the trigonal field of the nearest-neighbour Cr atoms (Fig. 1a) eliminates the local inversion symmetry of each Cr site, providing a static odd-parity field to allow the d–d transitions. We deduce that the absorbance of the $^4T_2$ transition is about 0.7% for monolayer CrI_3 (see Methods), which is an order of magnitude lower than the absorbance for the A and B excitonic resonances in monolayer semiconducting transition metal dichalcogenides[27], such as MoS_2. The weak absorption underscores the weakly allowed parity-forbidden nature of the d–d transition.

Our assignment of the reflection features is consistent with the results of prior experiments and recent calculations[28,29] on bulk $CrCl_3$ and $CrBr_3$. To connect these with CrI_3, in Fig. 4b, we
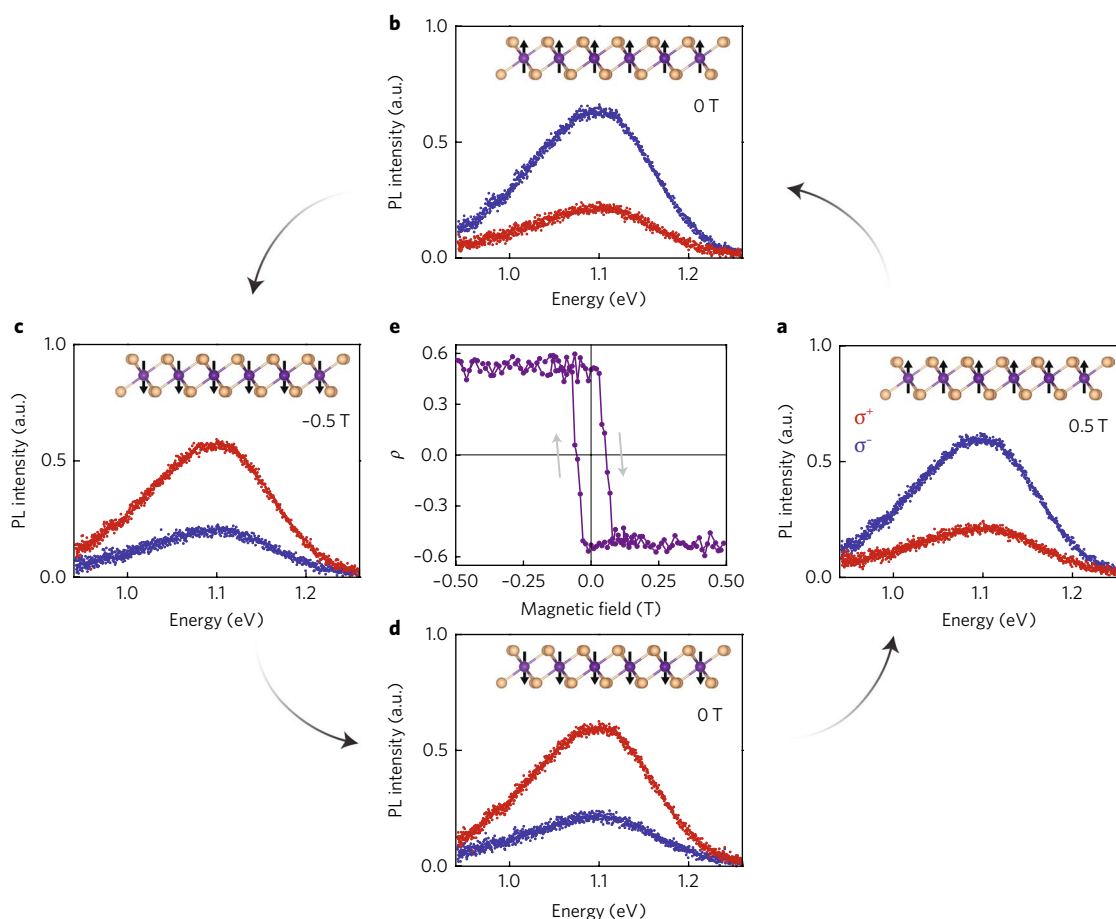
Fig. 2 | Photoluminescence from monolayer CrI₃ in an applied magnetic field. a–d, Sequence of PL spectra for σ⁺ (red) and σ⁻ (blue) circular polarization components, acquired at 15 K under linearly polarized excitation at magnetic fields of 0.5 T (increasing from 0 T) (**a**), 0 T (decreasing from 0.5 T) (**b**), −0.5 T (decreasing from 0 T) (**c**), and 0 T (increasing from −0.5 T) (**d**). The curved arrows indicate the magnetic field sweep direction, and the insets depict the magnetization direction relative to the lattice. **e,** Circular polarization (ρ) as a function of applied field over one full cycle. The grey arrows show the sweep direction of the applied field.

plot the absorption peak energies of bulk CrI_3 that we measured (Supplementary Section 4) against those of $CrCl_3$ and $CrBr_3$ from previous studies[13,19–22]. The relationship between the optical spectra of the Cr trihalides then becomes clear. The large energetic shift of the two high-energy peaks between different ligand species confirms their charge-transfer origin. On the other hand, the d–d transitions exhibit weaker dependence on the ligand. Interestingly, in view of the decreased ligand-field strength of I^- in CrI_3, we expect the lowest LMCT transition to overlap the highest d–d transition

($^4A_2$ to $^4T_1$). This suggests that the origin of the low-energy shoulder at 1.8 eV is absorption to the $^4T_1$ level, enhanced by its energetic proximity to the strong charge-transfer transitions near 2 eV. Thus, it is likely that both LMCT and d–d transitions play a role in the recently observed magneto-optical Kerr response[2] near 2 eV in few-layer CrI_3.

We can now begin to understand the origin of PL in atomically thin CrI_3. The clear correlation between the three Cr trihalide compounds in the energies of the lowest absorption peak and PL (Fig. 4b)
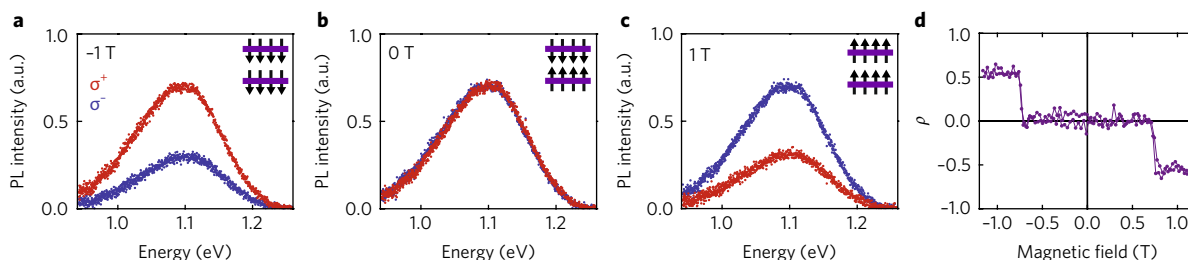

Fig. 3 | Bilayer luminescence reveals an antiferromagnetic ground state. a–c, PL spectrum of a bilayer sample for σ⁺ (red) and σ⁻ (blue) circular polarization and linearly polarized excitation acquired at 15 K at magnetic fields of −1 T (**a**), 0 T (**b**) and +1 T (**c**). The inset figures depict the inferred magnetization pattern of the bilayer. It should be noted that at 0 T the net magnetization is zero, but the exact spin orientation within each layer is unknown. **d,** Circular polarization (ρ) as a function of magnetic field. Data points for increasing and decreasing magnetic field overlap to within uncertainty. The data in **a–c** are from a bilayer on sapphire while the data in **d** are from a bilayer on SiO_2. Their behaviour is consistent.
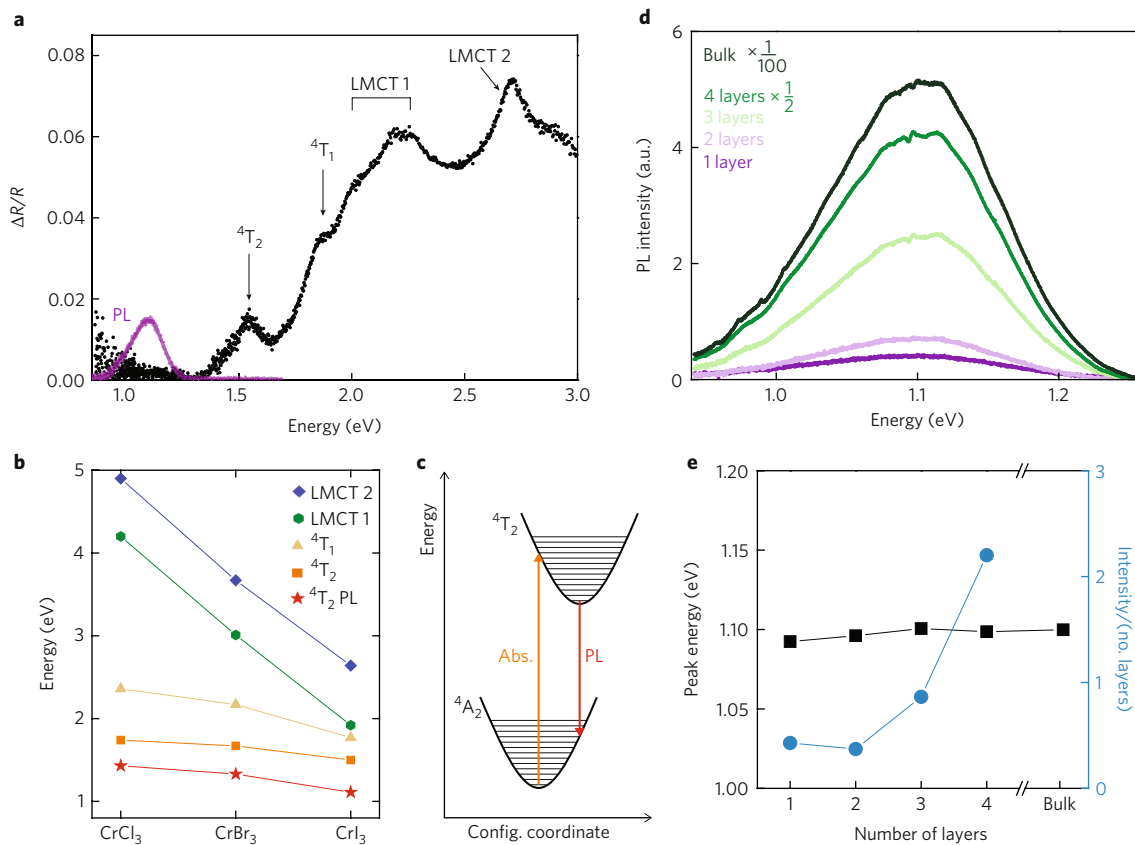
Fig. 4 | Reflection spectrum and thickness-dependent PL. a, Differential reflection spectrum of monolayer CrI_3 (black) and overlaid PL spectrum (purple). See the text for a discussion of the labelled peak assignments. **b**, Energies of the corresponding peaks in bulk $CrCl_3$, $CrBr_3$ and CrI_3. The CrI_3 data are from the sample in Supplementary Fig. 4, while the data for $CrBr_3$ and $CrCl_3$ are compiled from refs [13,19–22]. **c**, Configurational coordinate diagram in the harmonic approximation for the observed ligand-field $^4T_2$ absorption and PL. The horizontal lines represent vibrational levels. The calculated Huang–Rhys factor is ~10. **d**, Layer dependence of the PL spectra at 15 K and zero magnetic field. Note that the four-layer-thick and bulk spectra have been divided by a factor of 2 and 100 respectively. The small features near 1.08 eV are due to a slight artefact of the grating that could not be corrected. **e**, Peak energy (black) and PL intensity normalized by number of layers (blue) for different thicknesses. The peak energy is calculated by weighted average using the spectra in **d**.

implies that the monolayer CrI_3 PL arises from the $^4T_2$ to $^4A_2$ d–d transition. The ~400 meV Stokes shift between the PL and 1.5 eV reflection peak is a consequence of the Franck–Condon principle and strong electron–lattice coupling[26] (Fig. 4c, Huang–Rhys factor ~ 10, see Supplementary Section 5). The extracted ~1.3 eV $^4T_2$ zero-phonon energy is also consistent with the estimated ligand-field splitting of 1.2 eV determined from the angular overlap between the Cr–I σ and π bonds (Supplementary Section 5). The wide PL linewidth is a signature of d–d luminescence broadened by vibronic modes, characteristic of transition metal ions in solids[26]. This strong vibronic mixing precludes the formation of well-resolved phonon sidebands in the spectra[26]. In addition, our layer-dependent study demonstrates that the PL peak energy is independent of the thickness of CrI_3 (Fig. 4d,e), highlighting the localized nature of the ligand-field excitation. As the d–d transition is parity-forbidden, the observed PL intensity will sensitively depend on the origins of local symmetry breaking, such as from odd-parity phonons and trigonal distortion, and on the interactions with excited states and spin–orbit coupling. Determining the strengths of these interactions will be essential for understanding the relative intensity of the PL helicities observed in ferromagnetic CrI_3. We also note that PL intensity per layer (that is, normalized by the number of layers) increases with increasing thickness (Fig. 4e), suggesting that the d–d relaxation processes are affected by interlayer or substrate interactions.

The above measurements establish the prominence of highly localized optical excitations in atomically thin CrI_3. While transport measurements will be necessary to confirm its electrical properties, mono- and few-layer CrI_3 are likely to be good insulators, judging from the localized optical response and the large bulk resistivity[30]. The ligand-field luminescence helicity displays clear signatures of the underlying magnetic order, suggesting that the optical spectra will serve as an important probe of magnetic order in atomically thin CrI_3. Our results enlarge the landscape of light–matter interactions in 2D materials, and unlock new opportunities to study and control ligand-field spectra in the 2D limit in the presence of magnetic ordering. Further magneto-optical studies on the thickness and polarization dependence of the charge-transfer and ligand-field transitions may shed light on the nature of the intralayer and interlayer exchange interactions. Beyond this, our work previews exciting possibilities to use CrI_3 as an atomically thin magnetic insulator in van der Waals heterostructures. Complementary to the popular non-magnetic layered insulator hexagonal boron nitride, 2D CrI_3 will serve as a substrate, interfacial layer and tunnel barrier for engineering magnetic proximity effects, exploring spin-dependent tunnelling phenomena, and designing novel magneto-optoelectronic devices with spontaneous helical light emission.

Methods

Methods, including statements of data availability and any associated accession codes and references, are available at https://doi.org/10.1038/s41567-017-0006-7.

References

1. Dillon, J. F. & Olson, C. E. Magnetization, resonance, and optical properties of the ferromagnet CrI_3. *J. Appl. Phys.* **36**, 1259–1260 (1965).
2. Huang, B. et al. Layer-dependent ferromagnetism in a van der Waals crystal down to the monolayer limit. *Nature* **546**, 270–273 (2017).
3. Mak, K. F. & Shan, J. Photonics and optoelectronics of 2D semiconductor transition metal dichalcogenides. *Nat. Photon.* **10**, 216–226 (2016).
4. Xu, X., Yao, W., Xiao, D. & Heinz, T. F. Spin and pseudospins in layered transition metal dichalcogenides. *Nat. Phys.* **10**, 343–350 (2014).
5. Schaibley, J. R. et al. Valleytronics in 2D materials. *Nat. Rev. Mater.* **1**, 16055 (2016).
6. Snoek, J. L. *New Developments in Ferromagnetic Materials* (Elsevier, New York, 1947).
7. Tsubokawa, I. On the magnetic properties of a $CrBr_3$ single crystal. *J. Phys. Soc. Jpn* **15**, 1664–1668 (1960).
8. Wachter, P. The optical electrical and magnetic properties of the europium chalcogenides and the rare earth pnictides. *CRC Crit. Rev. Solid State Sci.* **3**, 189–241 (1972).
9. Baltzer, P. K., Lehmann, H. W. & Robbins, M. Insulating ferromagnetic spinels. *Phys. Rev. Lett.* **15**, 493–495 (1965).
10. Furdyna, J. K. Diluted magnetic semiconductors. *J. Appl. Phys.* **64**, R29–R64 (1988).
11. Ohno, H., Munekata, H., Penney, T., von Molnár, S. & Chang, L. L. Magnetotransport properties of p-type (In,Mn)As diluted magnetic III-V semiconductors. *Phys. Rev. Lett.* **68**, 2664–2667 (1992).
12. Ohno, H. et al. Ga,Mn)As: A new diluted magnetic semiconductor based on GaAs. *Appl. Phys. Lett.* **69**, 363–365 (1996).
13. Dillon, J. F., Kamimura, H. & Remeika, J. P. Magneto-optical properties of ferromagnetic chromium trihalides. *J. Phys. Chem. Solids* **27**, 1531–1549 (1966).
14. Burch, K. S., Awschalom, D. D. & Basov, D. N. Optical properties of III-Mn-V ferromagnetic semiconductors. *J. Magn. Magn. Mater.* **320**, 3207–3228 (2008).
15. Miles, P. A., Westphal, W. B. & Von Hippel, A. Dielectric spectroscopy of ferromagnetic semiconductors. *Rev. Mod. Phys.* **29**, 279–307 (1957).
16. Dietl, T. & Ohno, H. Dilute ferromagnetic semiconductors: Physics and spintronic structures. *Rev. Mod. Phys.* **86**, 187–251 (2014).
17. Gong, C. et al. Discovery of intrinsic ferromagnetism in 2D van der Waals crystals. *Nature* **546**, 265–269 (2017).
18. Lee, J.-U. et al. Ising-type magnetic ordering in atomically thin $FePS_3$. *Nano Lett.* **16**, 7433–7438 (2016).
19. Grant, P. M. & Street, G. B. Optical properties of the chromium trihalides in the region 1-11 eV. *Bull. Am. Phys. Soc. II* **13**, (1968).
20. Pollini, I. & Spinolo, G. Intrinsic optical properties of $CrCl_3$. *Phys. Status Solidi* **41**, 691–701 (1970).
21. Bermudez, V. M. & McClure, D. S. Spectroscopic studies of the two-dimensional magnetic insulators chromium trichloride and chromium tribromide—I. *J. Phys. Chem. Solids* **40**, 129–147 (1979).
22. Nosenzo, L., Samoggia, G. & Pollini, I. Effect of magnetic ordering on the optical properties of transition-metal halides: $NiCl_2$, $NiBr_2$, $CrCl_3$, and $CrBr_3$. *Phys. Rev. B* **29**, 3607–3616 (1984).
23. Figgis, B. N. & Hitchman, M. A. *Ligand Field Theory and its Applications* (Wiley, New York, 2000).
24. Tongay, S. et al. Defects activated photoluminescence in two-dimensional semiconductors: interplay between bound, charged, and free excitons. *Sci. Rep.* **3**, 2657 (2013).
25. McIntyre, J. D. E. & Aspnes, D. E. Differential reflection spectroscopy of very thin surface films. *Surf. Sci.* **24**, 417–434 (1971).
26. Henderson, B. & Imbusch, G. F. *Optical Spectroscopy of Inorganic Solids* (Clarendon, Oxford, 1989).
27. Li, Y. et al. Measurement of the optical dielectric function of monolayer transition-metal dichalcogenides: MoS_2, $MoSe_2$, WS_2, and WSe_2. *Phys. Rev. B* **90**, 205422 (2014).
28. Shinagawa, K., Sato, H., Ross, H. J., McAven, L. F. & Butler, P. H. Charge-transfer transitions in chromium trihalides. *J. Phys. Condens. Matter* **8**, 8457 (1996).
29. McAven, L. F., Ross, H. J., Shinagawa, K. & Butler, P. H. The Kerr magneto-optic effect in ferromagnetic $CrBr_3$. *J. Phys. B At. Mol. Opt. Phys.* **32**, 563 (1999).
30. McGuire, M. A., Dixit, H., Cooper, V. R. & Sales, B. C. Coupling of crystal structure and magnetism in the layered, ferromagnetic insulator CrI_3. *Chem. Mater.* **27**, 612–620 (2015).

Acknowledgements

Author contributions

X.X., K.L.S. and P.J.-H. conceived the experiment. K.L.S. built the experimental set-up and carried out the measurements, assisted by D.Z. and B.H., supervised by X.X. Crystal growth, characterization and device fabrication at MIT were carried out by D.R.K. and E.N.-M., supervised by P.J.-H. Device fabrication at UW was carried out by K.L.S., D.Z. and B.H., with crystal grown and characterized by M.A.M. at ORNL. K.L.S. and X.X. analysed and interpreted the data with theoretical support from X.Z., D.X., W.Y., S.G. and L.Y. K.L.S., X.X., D.H.C. and P.J.-H. wrote the manuscript with input from all authors. All authors discussed the results.

Competing financial interests

The authors declare no competing financial interests.

Additional information

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Methods

Sample fabrication. Bulk CrI$_3$ crystals were grown by chemical vapour transport, as described in detail in refs [2,30]. Monolayer and bilayer CrI$_3$ samples were then obtained by mechanical exfoliation from bulk CrI$_3$ onto a 0.5-mm-thick *c*-plane sapphire substrate in an Ar-filled glovebox. We also fabricated and measured samples on 285 nm SiO$_2$/Si (Supplementary Figs 1 and 3d). We confirmed the optical contrast of bilayer CrI$_3$ on sapphire by transferring a bilayer from 285 nm SiO$_2$/Si (on which the optical contrast has been established[2]) to sapphire. Thus, we determined the optical contrast on sapphire to be ~0.035 and ~0.07 at 631 nm for monolayer and bilayer CrI$_3$, respectively. Samples were kept under an inert atmosphere or vacuum during the entire fabrication and measurement process.

Optical measurements. Low-temperature optical measurements were performed in a closed-cycle cryostat with a superconducting magnet with the axis directed out of the sample plane. For the PL measurements, the sample was excited by a HeNe laser (632.8 nm) focused to a ~1 μm spot diameter. A low power of 10 μW was used to avoid sample heating and degradation. A dichroic beamsplitter reflected the collected PL, which was then spatially filtered through a confocal pinhole (to avoid collecting nearby bulk CrI$_3$ PL), dispersed by a 1.2 μm blaze grating, and detected by a liquid-nitrogen-cooled InGaAs linear photodiode array (Princeton Instruments). The InGaAs detector was spectrally calibrated using Hg emission lines. The excitation and detection polarization were controlled using linear polarizers and achromatic near-infrared half- and quarter-wave plates. Peak intensities were calculated by averaging 100 points (~30 meV) about the peak centre. For the white-light differential reflection measurements, we spatially filtered a tungsten halogen lamp through a pinhole and focused the beam to a ~3 μm spot size on the CrI$_3$. The reflected light was deflected with a beamsplitter and detected by a spectrometer and Si CCD (charge-coupled device) or InGaAs array, which enabled measurements from 1 to 3 eV. To obtain the differential reflectance, we subtracted and normalized the CrI$_3$ reflectance by the reflectance of the bare sapphire substrate. The $^4T_2$ absorbance was determined as $\frac{1}{4}(n^2-1)\frac{\Delta R}{R}$ (ref. [25]), where $n \approx 1.76$ is the ordinary refractive index of sapphire at 1.5 eV (ref. [31]).

Data availability. The data that support the plots within this paper and other findings of this study are available from the corresponding author upon reasonable request.

References

31. Malitson, I. H. Refraction and dispersion of synthetic sapphire. *J. Opt. Soc. Am.* **52**, 1377–1379 (1962).